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October 2001

FDS6892A

Dual N-Channel Logic Level PWM Optimized PowerTrench[®] MOSFET

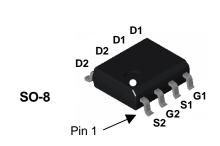
General Description

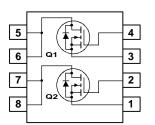
These N-Channel Logic Level MOSFETs are produced using Fairchild Semiconductor's advanced PowerTrench process that has been especially tailored to minimize the on-state resistance and yet maintain superior switching performance.

These devices are well suited for low voltage and battery powered applications where low in-line power loss and fast switching are required.

Features

- $\mbox{ } \mbox{ }$
- Low gate charge (12 nC)
- High performance trench technology for extremely low R_{DS(ON)}
- High power and current handling capability





Absolute Maximum Ratings T_{A=25°C} unless otherwise noted

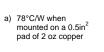
Symbol		Parameter		Ratings	Units
V _{DSS}	Drain-Sour	ce Voltage		20	V
V _{GSS}	Gate-Source	e Voltage		± 12	V
I _D	Drain Current – Continuous		(Note 1a)	7.5	А
	– Pulsed			30	
PD	Power Dissipation for Dual Operation			2	W
	Power Diss	ipation for Single Opera	tion (Note 1a)	1.6	
			(Note 1b)	1	
			(Note 1c)	0.9	
T _J , T _{STG}	Operating and Storage Junction Temperature Range		-55 to +150	°C	
Therma	l Charac	teristics			
R _{eja}	Thermal Re	esistance, Junction-to-Ar	mbient (Note 1a)	78	°C/W
R _{eJC}	Thermal Resistance, Junction-to-Case (Note 1)		ase (Note 1)	40	°C/W
Packag	e Markin	g and Ordering	Information		
Device Marking		Device	Reel Size	Tape width	Quantity
FDS6892A		FDS6892A	13"	12mm	2500 units

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FDS6892A

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Char	acteristics					
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0 V$, $I_D = 250 \mu A$	20			V
<u>ΔBV_{DSS}</u> ΔT _J	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$, Referenced to 25°C		5		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current				1 10	μA
I _{GSSF}	Gate-Body Leakage, Forward	$V_{GS} = 12 \text{ V}, V_{DS} = 0 \text{ V}$			100	nA
I _{GSSR}	Gate-Body Leakage, Reverse	$V_{GS} = -12 \text{ V}, V_{DS} = 0 \text{ V}$			-100	nA
On Char	acteristics (Note 2)					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$	0.6	0.9	1.5	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$, Referenced to 25°C		-3		mV/°0
R _{DS(on)}	Static Drain–Source	$V_{GS} = 4.5 \text{ V}, I_D = 7.5 \text{ A}$		13	18	mΩ
	On–Resistance	$V_{GS} = 2.5 \text{ V}, I_D = 6.5 \text{ A}$ $V_{GS} = 4.5 \text{ V}, I_D = 7.5 \text{ A}, T_J = 125^{\circ}\text{C}$		17 18	24 27	
I _{D(on)}	On–State Drain Current	$V_{GS} = 4.5V, V_{DS} = 5V$	15	10		А
9 _{FS}	Forward Transconductance	$V_{DS} = 5 V$, $I_{D} = 7.5 A$		37		S
Dvnamio	Characteristics					
C _{iss}	Input Capacitance	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V},$		1333		pF
C _{oss}	Output Capacitance	f = 1.0 MHz		301		pF
Crss	Reverse Transfer Capacitance	7		160		pF
Switchir	ng Characteristics (Note 2)					
t _{d(on)}	Turn–On Delay Time	$V_{DD} = 10 V, I_D = 1 A,$		8	16	ns
tr	Turn–On Rise Time	$V_{GS} = 4.5 \text{ V}, R_{GEN} = 6 \Omega$		15	27	ns
t _{d(off)}	Turn–Off Delay Time	7		26	42	ns
t _f	Turn–Off Fall Time			9	18	ns
Qg	Total Gate Charge	$V_{DS} = 10 \text{ V}, I_D = 7.5 \text{ A},$		12	17	nC
Q _{gs}	Gate-Source Charge	V _{GS} = 4.5 V		2.5		nC
Q _{gd}	Gate-Drain Charge			3		nC
Drain-S	ource Diode Characteristics	and Maximum Ratings				
Is	Maximum Continuous Drain–Source Diode Forward Current				1.3	Α
	Drain-Source Diode Forward	$V_{GS} = 0 V$, $I_{S} = 1.3 A$ (Note 2)		0.7	1.2	V







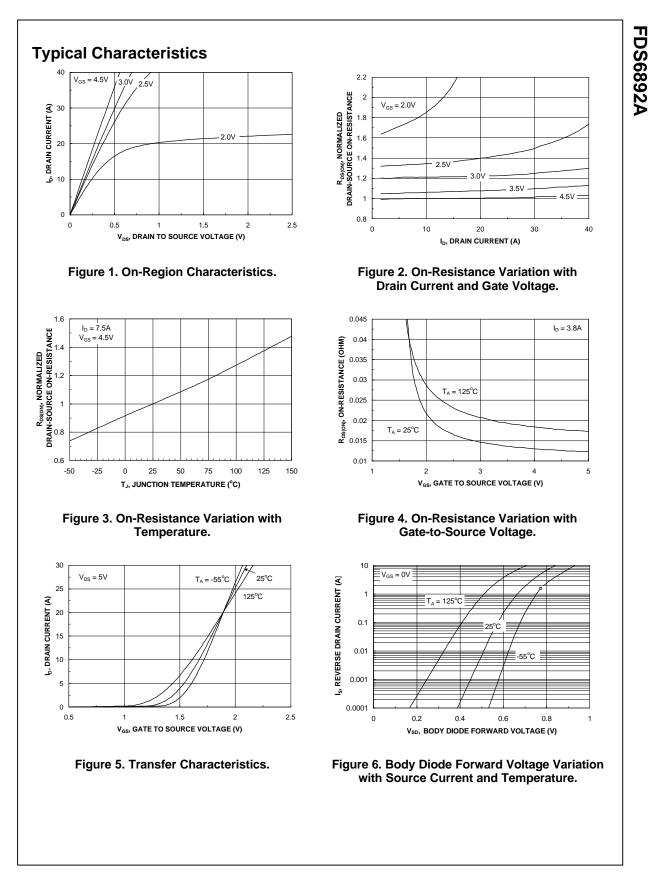




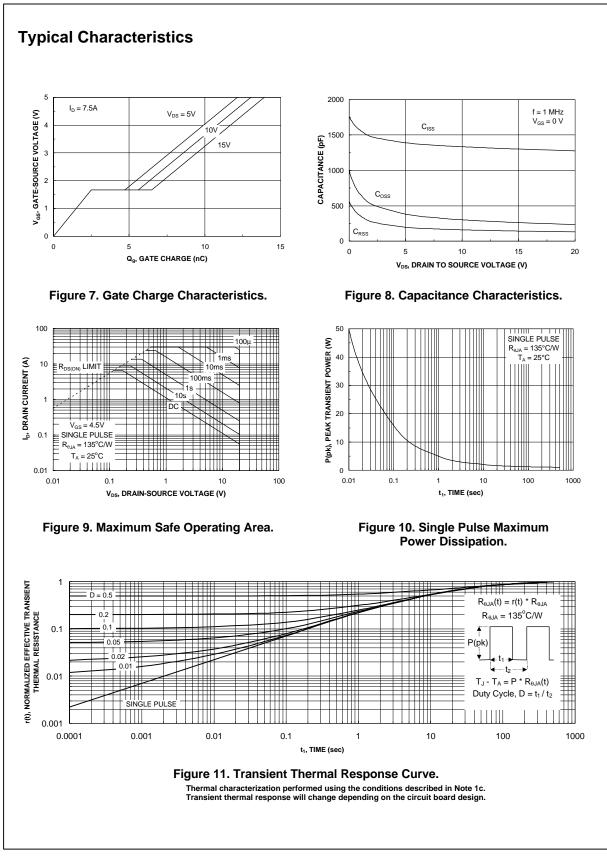
c) 135°C/W when mounted on a minimum mounting pad.



2. Pulse Test: Pulse Width < 300 μ s, Duty Cycle < 2.0%



FDS6892A Rev C (W)



FDS6892A

FDS6892A Rev C (W)

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